

N-channel TrenchMOS standard level FET

Rev. 02 — 22 February 2008

Product data sheet

1. Product profile

1.1 General description

Standard level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using Nexperia General Purpose Automotive (GPA) TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

1.2 Features

- 175 °C rated
- Q101 compliant

1.3 Applications

- 12 V, 24 V and 42 V loads
- General purpose power switching
- Low on-state resistance
- Standard level compatible
- Automotive systems
- Motors, lamps and solenoids

1.4 Quick reference data

Table 1. Quick reference

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25 ~^\circ C; ~T_j \leq 175 ~^\circ C$		-	-	75	V
I _D	drain current	$V_{GS} = 10 \text{ V}; T_{mb} = 25 \text{ °C};$ see <u>Figure 1</u> and <u>4</u>	[1]	-	-	45	A
P _{tot}	total power dissipation	T _{mb} = 25 °C; see Figure 2		-	-	158	W
Tj	junction temperature			-55	-	175	°C
Static ch	aracteristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; see <u>Figure 12</u> and <u>13</u>		-	22	26	mΩ
Avalanch	ne ruggedness						
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$\begin{array}{l} I_{D}=45 \; A; \; V_{sup} \leq 75 \; V; \\ R_{GS}=50 \; \Omega; \; V_{GS}=10 \; V; \\ T_{j(init)}=25 \; ^{\circ}C; \; unclamped \\ inductive \; load \end{array}$		-	-	215	mJ

[1] Capped at 45 A due to bondwire.

nexperia

2. Pinning information

Table 2.	Pinning			
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain		$\dot{\frown}$
3	S	source		G_(IET)
mb	D	mounting base; connected to drain	SOT428 (DPAK)	mbb076 S

3. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BUK7226-75A	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428			

4. Limiting values

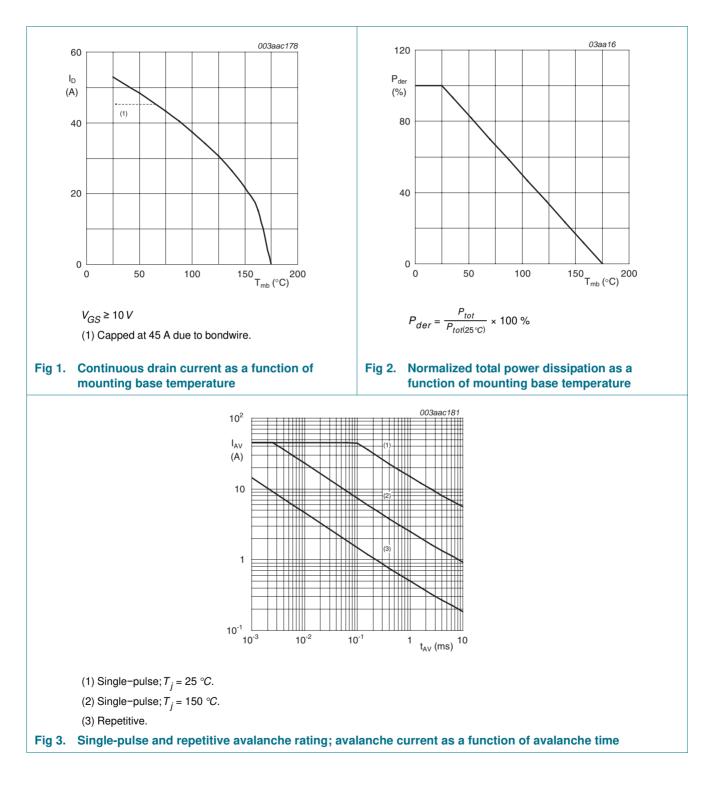
Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

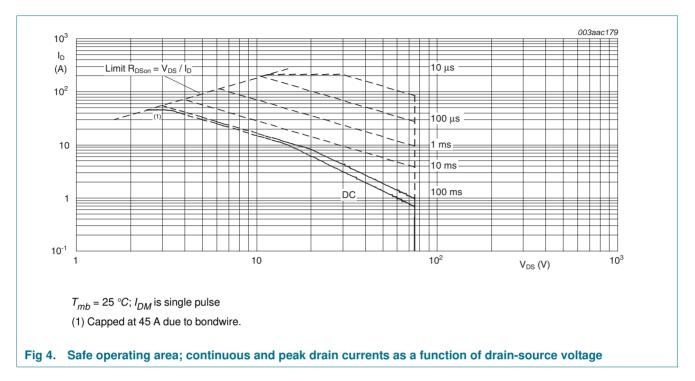
Symbol	Daramatar	Conditiono	Min	Мах	Unit
Symbol	Parameter	Conditions	IVIIII	-	Unit
V _{DS}	drain-source voltage	$T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}$	-	75	V
V_{DGR}	drain-gate voltage	R_{GS} = 20 k Ω	-	75	V
V_{GS}	gate-source voltage		-20	20	V
I _D	drain current	T_{mb} = 25 °C; V_{GS} = 10 V; see <u>Figure 1</u> and <u>4</u>	<u>[1]</u> -	45	А
		T_{mb} = 100 °C; V_{GS} = 10 V; see <u>Figure 1</u>	-	38	А
I _{DM}	peak drain current	T_{mb} = 25 °C; $t_p \leq$ 10 $\mu s;$ pulsed; see Figure 4	-	215	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>	-	158	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
Avalanc	he ruggedness				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$\begin{array}{l} I_D = 45 \; A; \; V_{sup} \leq 75 \; V; \; R_{GS} = 50 \; \Omega; \\ V_{GS} = 10 \; V; \; T_{j(init)} = 25 \; ^{\circ}C; \; unclamped \\ inductive \; load \end{array}$	-	215	mJ
E _{DS(AL)R}	repetitive drain-source avalanche energy	see <u>Figure 3</u>	[2][3] [4]	-	J
Source-o	drain diode				
l _S	source current	T _{mb} = 25 °C	[1] -	45	А
I _{SM}	peak source current	$t_p \le 10 \ \mu s$; pulsed; T_{mb} = 25 °C	-	215	А
		-			

[1] Capped at 45 A due to bondwire.

- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [3] Repetitive avalanche rating limited by an average junction temperature of 170 °C.
- [4] Refer to application note AN10273 for further information.



BUK7226-75A



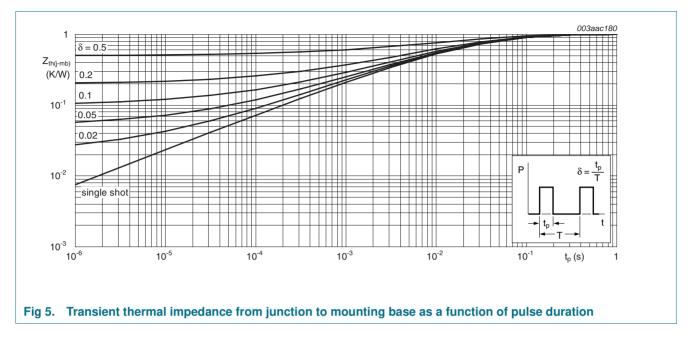
Thermal characteristics 5.

Table 5.	Thermal characteristic	cs				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	minimum footprint; FR4 board	-	70	-	K/W
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	see <u>Figure 5</u>	-	-	1	K/W

Nexperia

N-channel TrenchMOS standard level FET

BUK7226-75A

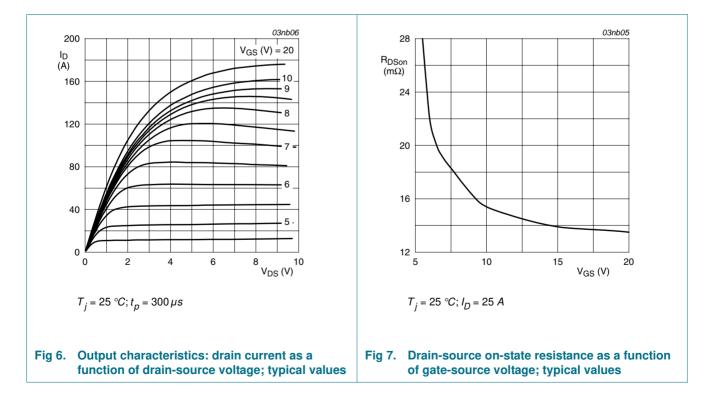


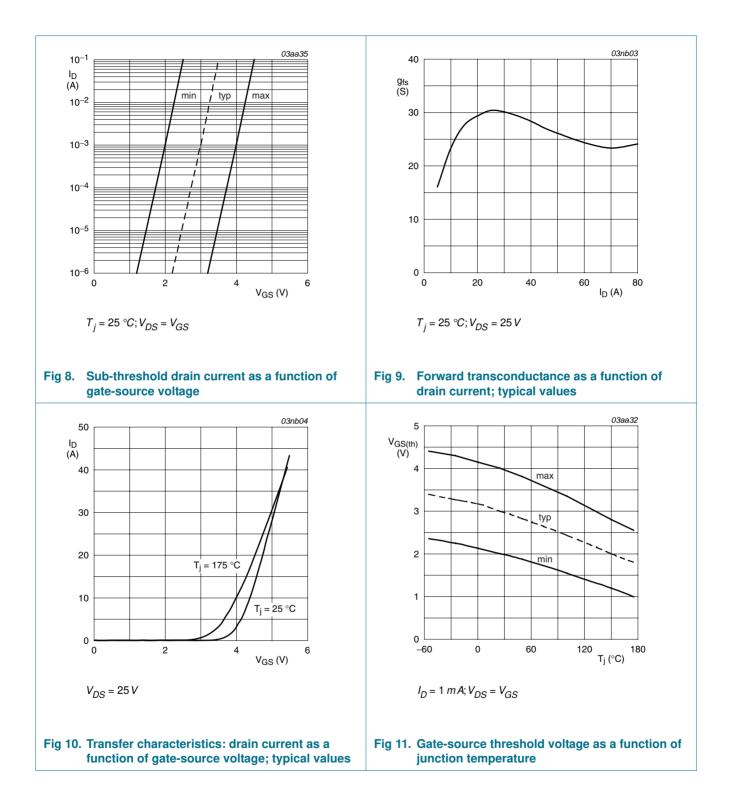
6. Characteristics

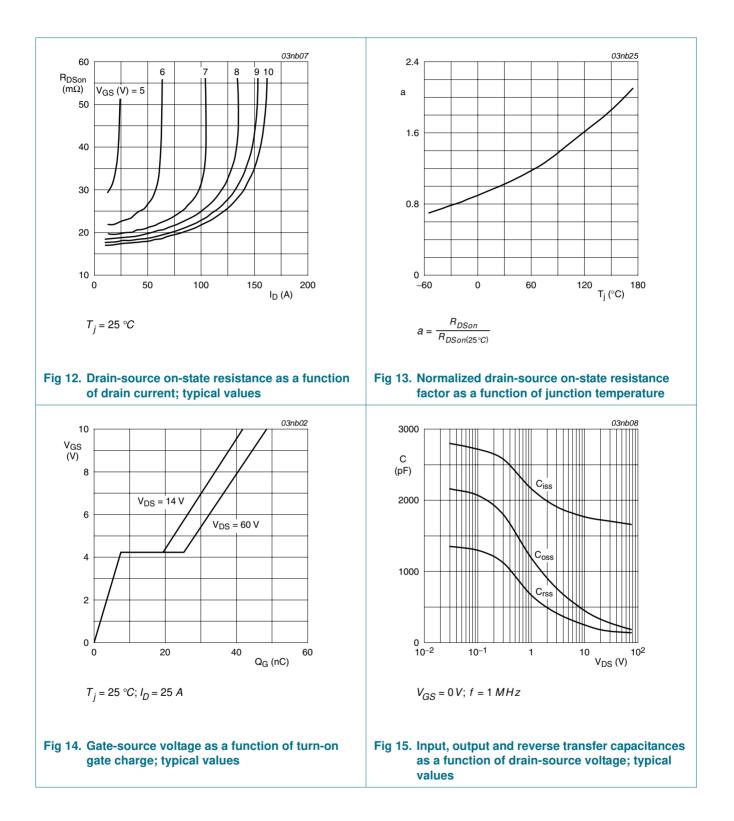
Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$\label{eq:ID} \begin{array}{l} I_D = 0.25 \text{ mA}; \ V_{GS} = 0 \ V; \\ T_j = -55 \ ^\circ\text{C} \end{array}$	70	-	-	V
		$\label{eq:ID} \begin{array}{l} I_D = 0.25 \text{ mA}; \ V_{GS} = 0 \ V; \\ T_j = 25 \ ^\circ\text{C} \end{array}$	75	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 175 °C; see <u>Figure 11</u>	1	-	-	V
		$\begin{split} I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}; \\ \text{see } \underline{\text{Figure 11}} \end{split}$	2	3	4	V
		$\begin{split} I_D &= 1 \text{ mA; } V_{DS} = V_{GS}; \\ T_j &= -55 ^\circ\text{C}\text{; see } \frac{\text{Figure 11}}{1} \end{split}$	-	-	4.4	V
I _{DSS}	drain leakage current	V_{DS} = 75 V; V_{GS} = 0 V; T_j = 25 °C	-	0.05	10	μA
		V _{DS} = 75 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	V_{DS} = 0 V; V_{GS} = 20 V; T_j = 25 °C	-	2	100	nA
		V_{DS} = 0 V; V_{GS} = -20 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A};$ $T_j = 175 \text{ °C}; \text{ see } \frac{\text{Figure } 12}{13} \text{ and } \frac{13}{13}$	-	-	54	mΩ
		$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ °C};$ see <u>Figure 12</u> and <u>13</u>	-	22	26	mΩ
Source-d	rain diode					
V _{SD}	source-drain voltage	$I_{S} = 25 \text{ A}; \text{ V}_{GS} = 0 \text{ V}; \text{ T}_{j} = 25 \text{ °C};$ see Figure 16	-	0.85	1.2	V
3UK7226-75A 2					© Nexperia B.V. 20)17. All rights res

© Nexperia B.V. 2017. All rights reserved

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{rr}	reverse recovery time	$I_{S} = 20 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s};$	-	53	-	ns
Qr	recovered charge	V_{GS} = -10 V; V_{DS} = 30 V; T _j = 25 °C	-	144	-	nC
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 60 \text{ V};$	-	48	-	nC
Q _{GS}	gate-source charge	$V_{GS} = 10 V$; see Figure 14	-	7.5	-	nC
Q _{GD}	gate-drain charge		-	17	-	nC
C _{iss}	input capacitance	$V_{GS} = 0 V; V_{DS} = 25 V;$	-	1789	2385	pF
C _{oss}	output capacitance	f = 1 MHz; T _j = 25 °C; see Figure 15	-	382	458	pF
C _{rss}	reverse transfer capacitance		-	219	300	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 30 \text{ V}; \text{ R}_{L} = 1.2 \Omega;$	-	14	-	ns
t _r	rise time	$V_{GS} = 10 \text{ V}; \text{ R}_{G(ext)} = 10 \Omega;$	-	66	-	ns
t _{d(off)}	turn-off delay time	– T _j = 25 °C –	-	61	-	ns
t _f	fall time		-	41	-	ns
L _D	internal drain inductance	measured from drain lead from package to center of die; $T_j = 25 \ ^{\circ}C$	-	2.5	-	nH
L _S	internal source inductance	measured from source lead from package to source bond pad; $T_i = 25 \ ^{\circ}C$	-	7.5	-	nH



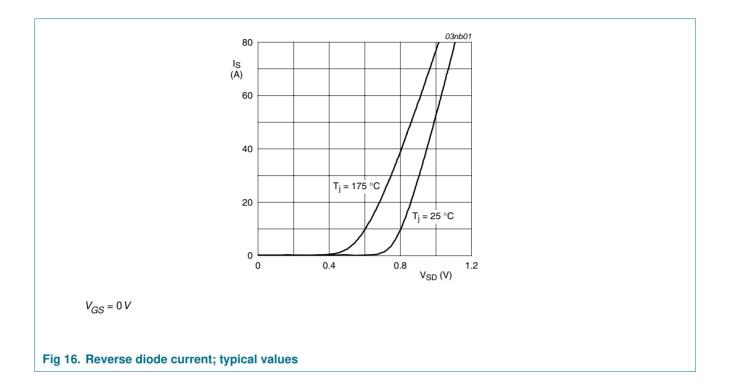




Nexperia

N-channel TrenchMOS standard level FET

BUK7226-75A



N-channel TrenchMOS standard level FET

7. Package outline

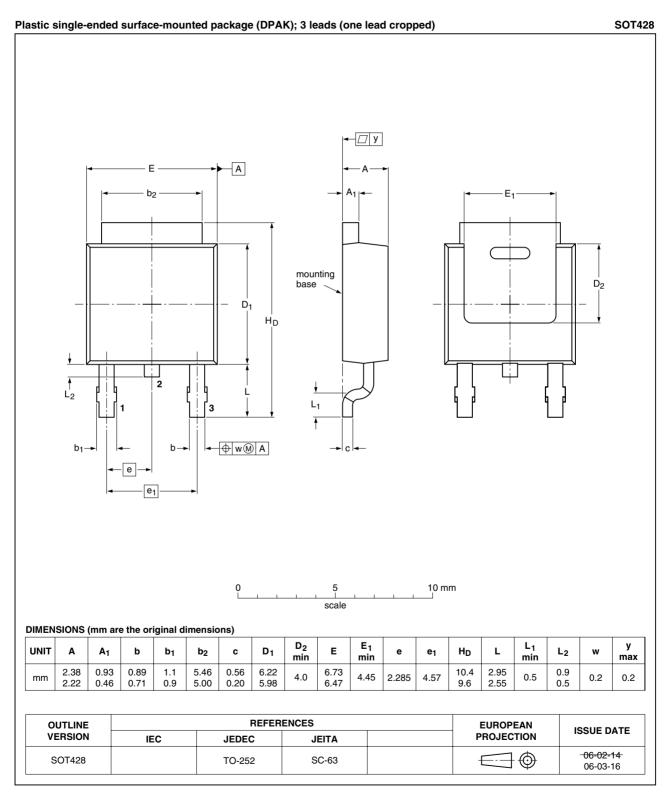


Fig 17. Package outline SOT428 (DPAK)

8. Revision history

Table 7. Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BUK7226-75A_2	20080222	Product data sheet	-	BUK7226_75A-01
Modifications:	guidelines o	of this data sheet has been of NXP Semiconductors.		-
	 Legal texts 	have been adapted to the	new company name whe	ere appropriate.
BUK7226_75A-01	20001009	Product specification; in	itial version	-

9. Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

9.2 **Definitions**

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

9.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia accepts no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <u>http://www.nexperia.com/profile/terms</u>, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by Nexperia. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

9.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

10. Contact information

For additional information, please visit: http://www.nexperia.com

For sales office addresses, send an email to: salesaddresses@nexperia.com

11. Contents

1	Product profile 1
1.1	General description 1
1.2	Features
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Limiting values 2
5	Thermal characteristics 4
6	Characteristics 5
7	Package outline 10
8	Revision history 11
9	Legal information 12
9.1	Data sheet status 12
9.2	Definitions 12
9.3	Disclaimers 12
9.4	Trademarks 12
10	Contact information 12
11	Contents 13